

FEATURES

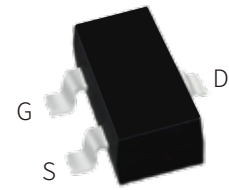
Ultra low on-resistance: $V_{DS}=20V, R_{DS(ON)} \leq 40m\Omega$

@ $V_{GS}=4.5V, I_D=3A$

For Low power DC to DC converter application

For Load switch application

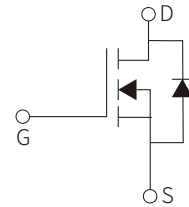
Surface Mount device



SOT-23



Marking



Schematic Symbol

APPLICATION

Case: SOT-23

Case Material: Molded Plastic. UL flammability

Classification Rating: 94V-0

APPROVALS

RoHS Compliance with 2011/65/EU

HF Compliance with IEC61249-2-21:2003

ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	20	V
Continuous drain current	I_D	3	A
Pulsed drain current (Note 1)	I_{DM}	12	A
Gate-Source Voltage	V_{GS}	± 10	V
Power dissipation	P_D	1.0	W
Thermal resistance from Junction to ambient	$R_{\theta JA}$	125	$^\circ\text{C}/\text{W}$
Junction temperature	T_J	150	$^\circ\text{C}$
Storage temperature	T_{STG}	-55 to 150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS($T_a=25^{\circ}\text{C}$)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Drain-source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=10\mu A$	20			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=20V, V_{GS}=0V$			1	μA
Gate-Body Leakage	I_{GSS}	$V_{GS}=\pm 10V, V_{DS}=0V$			± 100	nA
Gate Threshold Voltage(note 1)	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	0.4		1.2	V
Drain-source on-resistance (note 1)	$R_{DS(on)}$	$V_{GS}=4.5V, I_D=3.0A$		40	55	m Ω
		$V_{GS}=2.5V, I_D=2.0A$		55	80	
Forward transconductance (note 1)	g_{FS}	$V_{DS}=5V, I_D=3.0A$		8.5		S
Input Capacitance	C_{iss}	$V_{DS}=10V, V_{GS}=0V, f=1.0MHz$		237		pF
Output Capacitance	C_{oss}			80		
Reverse Transfer Capacitance	C_{rss}			35		
Turn-On Delay Time	$t_{d(on)}$	$V_{GS}=4.5V, I_D=3A$ $V_{DD}=10V, R_{GEN}=6\Omega$		23		ns
Turn-On Rise Time	t_r			11		
Turn-Off Delay Time	$t_{d(off)}$			34		
Turn-Off Fall Time	t_f			36		
Diode forward voltage(note 1)	V_{SD}	$I_S=3.0A, V_{GS}=0V$			1.2	V
Total Gate Charge	Q_g	$V_{GS}=4.5V, V_{DD}=10V, I_D=3A$		2.7		nC
Gate Source Charge	Q_{gs}			0.4		
Gate Drain Charge	Q_{gd}			0.8		
Diode forward current	I_S				3.0	A

Note:1. Pulse test ; Pulse width $\leq 300\mu s$, Duty cycle $\leq 2\%$

PARAMETER CHARACTERISTIC CURVE

Fig 1: Power Dissipation

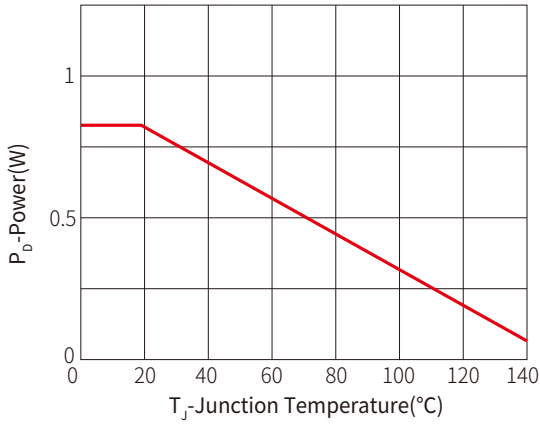


Figure 2: Drain Current

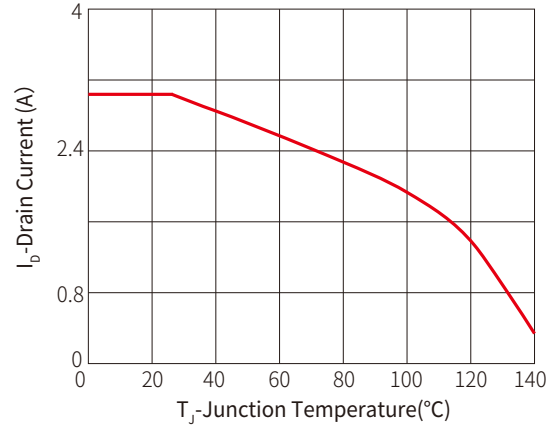


Figure 3: Output Characteristics

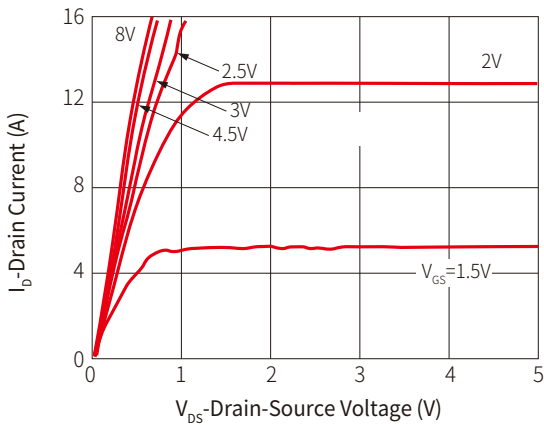


Figure 4: Drain-Source On-Resistance

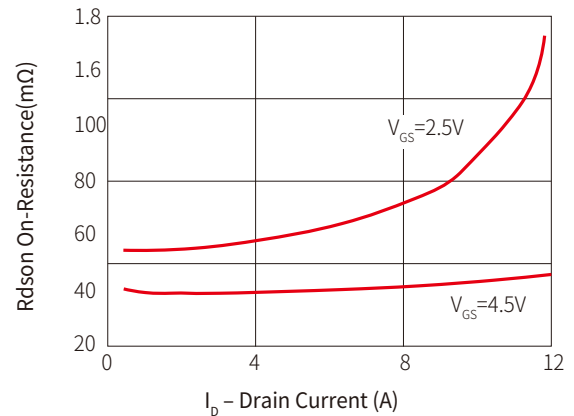


Figure 5: Transfer Characteristics

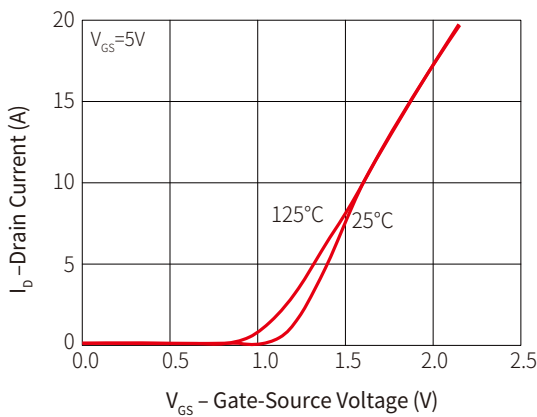


Figure 6: Drain-Source On-Resistance

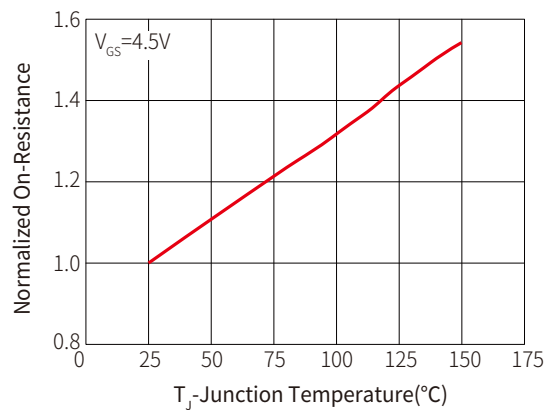


Figure 7: Rdson vs Vgs

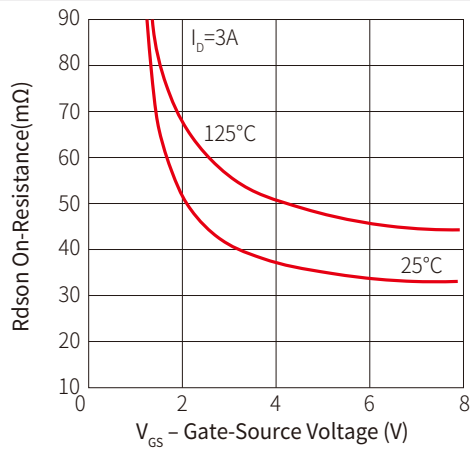


Figure 8: Capacitance vs Vds

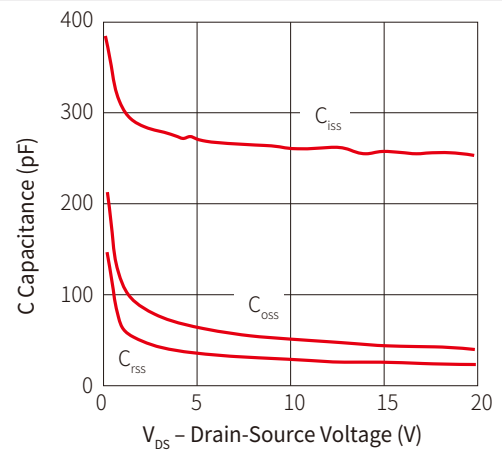


Figure 9: Gate Charge

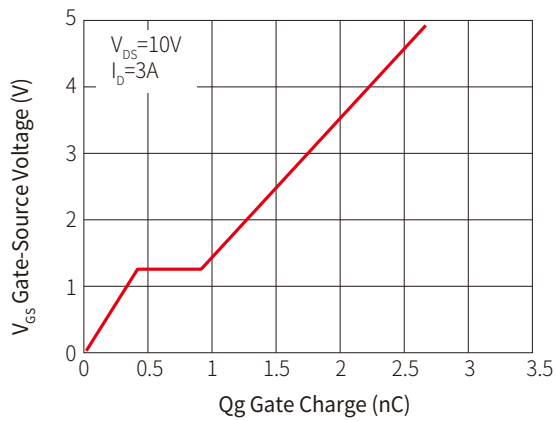


Figure 10: Source- Drain Diode Forward

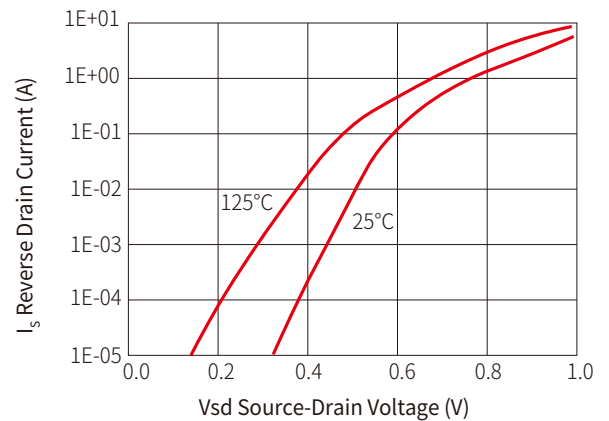
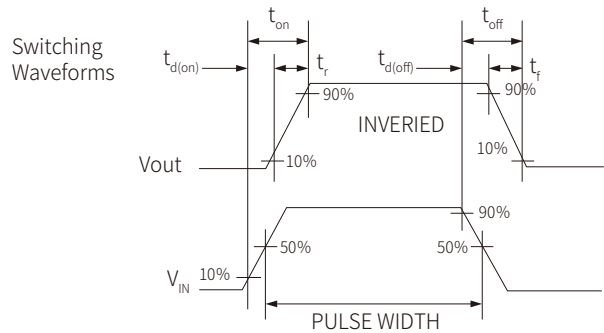
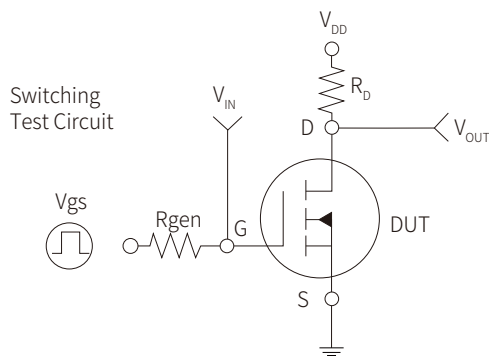
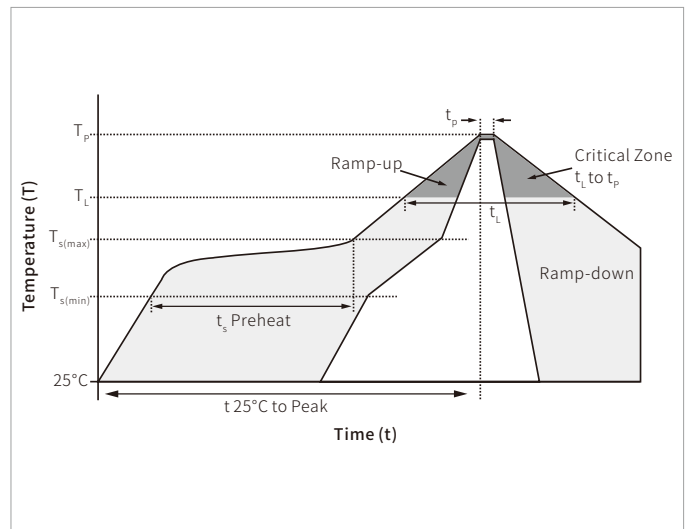


Figure 11: Typical Electrical and Thermal Characteristics

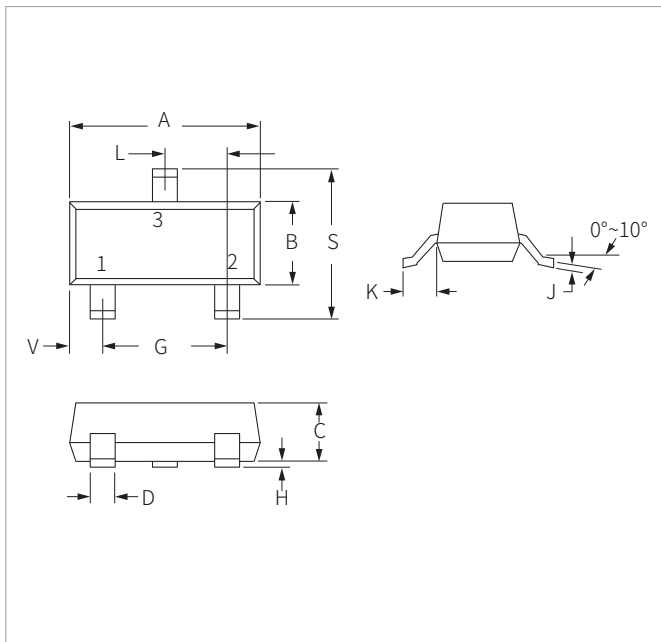


SOLDERING PARAMETERS

Reflow Condition		Lead-free assembly
Pre Heat	Temperature Max ($T_{s(min)}$)	150°C
	Temperature Max ($T_{s(max)}$)	200°C
	Time (min to max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus Temp (T_L) to peak		3°C/second max
$T_{s(max)}$ to T_L - Ramp-up Rate		3°C/second max
Reflow	Temperature (T_L) (Liquidus)	217°C
	Time (min to max) (t_L)	60 – 150 seconds
Peak Temperature (T_p)		260°C
Time within 5°C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		6°C/second max
Time 25°C to peak Temperature (T_p)		8 minutes max.
Do not exceed		260°C

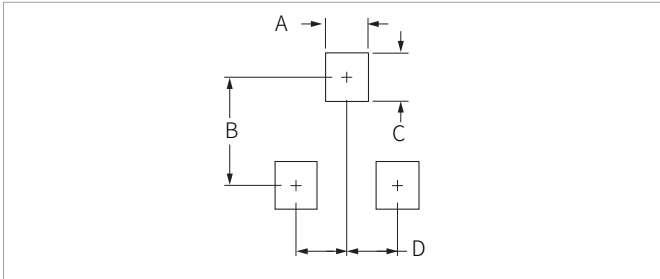


SOT-23 PACKAGE INFORMATION



Ref.	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	2.80	3.05	0.110	0.120
B	1.20	1.40	0.047	0.055
C	0.90	1.15	0.035	0.045
D	0.37	0.50	0.015	0.020
G	1.75	2.05	0.069	0.081
H	0.01	0.100	0.001	0.004
J	0.085	0.180	0.003	0.007
K	0.35	0.69	0.014	0.029
L	0.89	1.02	0.035	0.040
S	2.10	2.65	0.083	0.104
V	0.45	0.60	0.018	0.024

RECOMMENDED PAD LAYOUT DIMENSIONS



Ref.	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	0.71	0.97	0.028	0.038
B	1.88	2.13	0.074	0.084
C	0.71	0.97	0.028	0.038
D	0.81	1.07	0.032	0.042

ORDERING INFORMATION

Part Number	Component Package	QTY/Reel	Reel Size
SNM2302S	SOT-23	3000PCS	7"

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